FAIRCHILD

SEMICONDUCTOR®

BF199

NPN RF Transistor



1. Collector 2. Emitter 3. Base

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Absolute Maximum Ratings* $T_C=25$ °C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	25	V
V _{CBO}	Collector-Base Voltage	40	V
V _{EBO}	Emitter-Base Voltage	4.0	V
I _C	Collector Current - Continuous	50	mA
T _J , T _{STG}	Operating and Storage Junction Temperature Range	- 55 ~ 150	°C

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

Electrical Characteristics T_C=25°C unless otherwise noted

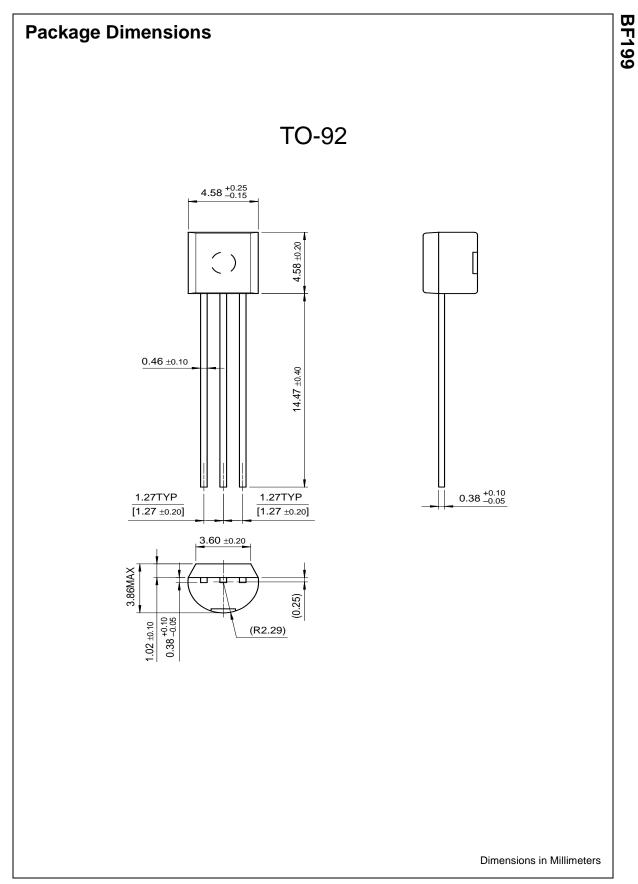
Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Characte	eristics	÷	•		
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage *	$I_{\rm C} = 1.0 {\rm mA}, I_{\rm B} = 0$	25		V
V _{(BR)CBO}	Collector-Base BreakdownVoltage	$I_{\rm C} = 100 \mu {\rm A}, I_{\rm E} = 0$	40		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{\rm E} = 10\mu A, I_{\rm C} = 0$	4.0		V
ICES	Collector Cut-off Current	$V_{CE} = 30V, I_E = 0$		50	nA
On Characte	eristics	÷	•		
h _{FE}	DC Current Gain	I _C = 7.0mA, V _{CE} = 10V	38		
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 10mA, I _B = 5.0mA		0.2	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C = 10mA, I _B = 5.0mA		0.92	V
V _{BE} (on)	Base-Emitter On Voltage	I _C = 7.0mA, V _{CE} = 10V		0.925	V
Small Signa	I Characteristics	÷	•		
f _T	Current gain Bandwidth Product	I _C = 7.0mA, V _{CE} = 10V, f = 100MHz		1100	MHz
C _{re}	Common-Emitter Ruerse Transfer Capacitance	V _{CB} = 10V, I _E = 0, f = 1.0MHz		0.4	pF

* Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2.0%

Thermal Characteristics $T_A=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation	350	mW
-	Derate above 25°C	2.8	mW/°C
R _{θJC}	Thermal Resistance, Junction to Case	125	°C/W
R _{θJA}	Thermal Resistance, Junction to Ambient	357	°C/W

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